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Product Data Sheet

## **Industrial USB Flash Drive**

### **U-50k Series**

USB 3.1 SuperSpeed, MLC

Commercial and Industrial  
Temperature Grade

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# U-50k Series – Industrial USB Flash Drive

## 16 GBytes up to 128 GBytes

### 1. Product Summary

- **Capacities:** 16 GBytes, 32 GBytes, 64 GBytes, 128 GBytes
- **Form Factor:** USB3.1 solid state flash drive with USB Type-A connector (68 mm x 18 mm x 8.3 mm)
- **Compliance:** USB 3.1 Gen 1 SuperSpeed specification compatible (backward compliance with USB 2.0/1.1)
- **Performance:**
  - Read Performance: Sequential Read up to 153 MBytes/s, Random Read IOPS up to 3,220
  - Write Performance: Sequential Write up to 64 MBytes/s, Random Write IOPS up to 930
- **Operating Temperature Range <sup>1</sup>:**
  - Commercial: 0 °C to 70 °C
  - Industrial: -40 °C to 85 °C
- **Storage Temperature Range:** -40 °C to 85 °C
- **Operating Voltage:** 5.0 V ± 10%
- **Data Retention:** 10 Years @ Life Begin; 1 Year @ Life End
- **Endurance in TeraBytes Written (TBW) @ Max Capacity:** 396 (seq. write 128KB); 10.7 (random write 4KB)
- **High-Performance 32-Bit Processor with Integrated, Parallel Flash Interface Engines:**
  - Multi-Level Cell (MLC) NAND Flash
  - Hardware BCH Code ECC (up to 40bit correction per 1 KByte page)
- **High Reliability:**
  - Mean Time Between Failure (MTBF): > 3,000,000 hours
  - Data Reliability: < 1 non-recoverable error per 10<sup>16</sup> bits read

<sup>1</sup> Adequate airflow is required to ensure the drive temperature, as reported in the S.M.A.R.T. data, does not exceed the specified maximum operating temperature.

## 2. Product Features

- Page based Flash management with **durabit™** technology for increased endurance & random performance
- Optimized FW algorithms especially for high read access and long data retention applications
  - Proven power fail management for highest reliability
  - Near Miss ECC technology  
Minimize the risk of uncorrectable bit failure over the product life time. Each read command analyzes the ECC margin level and refreshes data if necessary.
  - Read Disturb Management  
The read commands are monitored and the content is refreshed when critical levels have occurred.
  - Wear Leveling technology  
Equal wear leveling of static and dynamic data. The wear leveling assures that dynamic data as well as static data is balanced evenly across the memory. This guarantees the maximum write endurance of the device.
  - Data Care Management  
The interruptible background process controls the user data for read disturb effects or high temperature related retention degradation and refreshes data if necessary.
- Detailed S.M.A.R.T. support and extended vendor information
- LED for operation indication
- In-field firmware update
- 30 µinch gold-plated USB 3.0 Type-A connector contacts
- Swissbit Life Time Monitoring (SBLTM) tool and SDK for SBLTM (on request)
- Controlled BOM & PCN process
- Customized options like removable or fixed drive configuration, customer specified strings and IDs, laser marking, FAT16, FAT32 or customer file system, preload service or customized logo on request



### 3. Ordering Information

**Table 1: Standard Product List**

Capacity	Temperature	
	Commercial	Industrial
	Part Number	Part Number
16 GBytes	SFU3016GExAE2T0-C-GS-1y1-STD	SFU3016GExAE2T0-I-GS-1y1-STD
32 GBytes	SFU3032GExAE2T0-C-GS-1y1-STD	SFU3032GExAE2T0-I-GS-1y1-STD
64 GBytes	SFU3064GExAE2T0-C-LT-1y1-STD	SFU3064GExAE2T0-I-LT-1y1-STD
128 GBytes	SFU3128GExAE1T0-C-OC-1y1-STD	SFU3128GExAE1T0-I-OC-1y1-STD

x = product generation and y = firmware revision

**Table 2: Available Part Numbers**

Capacity	Temperature	
	Commercial	Industrial
	Part Number	Part Number
16 GBytes	SFU3016GE1AE2T0-C-GS-1A1-STD	SFU3016GE1AE2T0-I-GS-1A1-STD
16 GBytes	SFU3016GE1AE2T0-C-GS-1B1-STD	SFU3016GE1AE2T0-I-GS-1B1-STD
32 GBytes	SFU3032GE1AE2T0-C-GS-1A1-STD	SFU3032GE1AE2T0-I-GS-1A1-STD
32 GBytes	SFU3032GE1AE2T0-C-GS-1B1-STD	SFU3032GE1AE2T0-I-GS-1B1-STD
64 GBytes	SFU3064GE1AE2T0-C-LT-1A1-STD	SFU3064GE1AE2T0-I-LT-1A1-STD
64 Gbytes	SFU3064GE1AE2T0-C-LT-1B1-STD	SFU3064GE1AE2T0-I-LT-1B1-STD
128 GBytes	SFU3128GE1AE1T0-C-OC-1A1-STD	SFU3128GE1AE1T0-I-OC-1A1-STD
128 GBytes	SFU3128GE1AE1T0-C-OC-1B1-STD	SFU3128GE1AE1T0-I-OC-1B1-STD

## 4. Product Description

The Swissbit U-50k USB 3.1 embedded USB flash drive provides a robust, high performance, and reliable storage product with industry compatible interface and small form factor. The U-50k MLC technology both enables high NAND flash operation and excellent endurance. The use of page based Flash management and a global wear leveling extends the endurance to unprecedented values for USB products.

The standard USB3 Type-A connector allows easy operation with USB3 or USB2 Type-A sockets.

For outdoor use or in poorly ventilated systems the U-50k is available in industrial temperature grade from -40°C to +85°C. Each individual industrial temperature grade drive is tested at these corners to verify the temperature resistance.

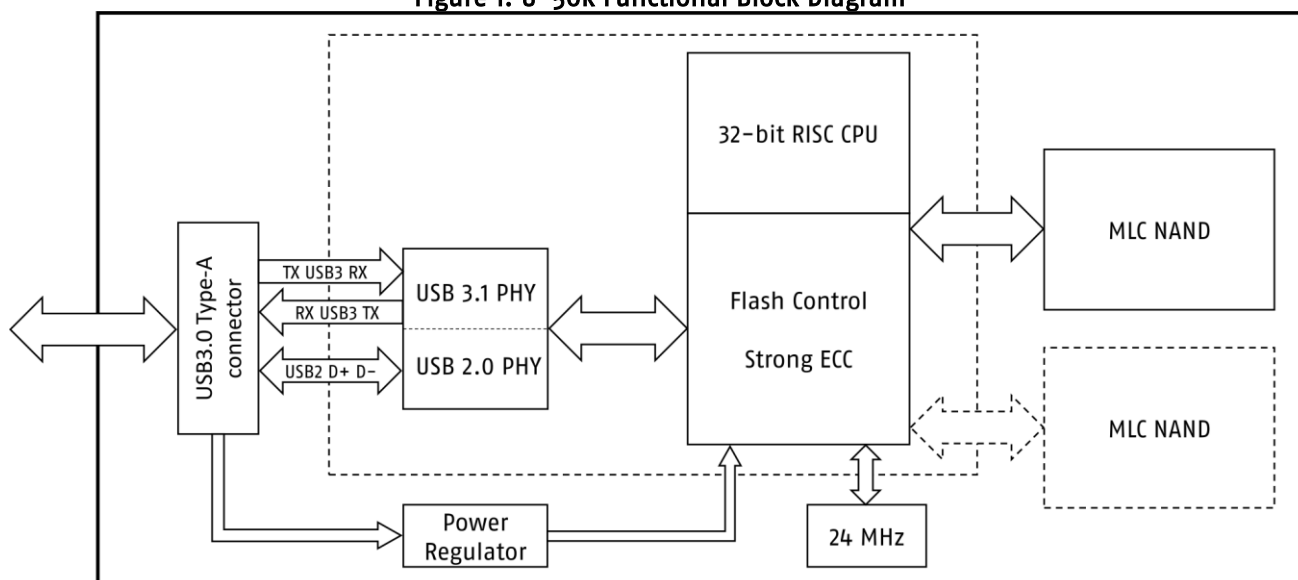
The U-50k firmware includes data care management features which refresh storage areas that are not or only infrequently read. At high temperature storage these areas are prone to retention loss. The firmware monitors the state of the NAND blocks and refreshes those that show a high level of degradation, thus preventing uncorrectable errors. This is an important feature for USB flash drives that are used as read only boot media.

The U-50k consists of a high performance 32bit RISC USB controller, the USB-A connector, power circuitry and different numbers of NAND dies. The U-50k keys use two flash channels for best performance.

The U-50k operates at 5V nominal with  $\pm 10\%$  tolerance.

It supports USB 3.1 Gen 1 SuperSpeed and is fully backwards compatible to USB 2.0/1.1 High/Full Speed.

Figure 1: U-50k Functional Block Diagram



## 4.1 Performance Specifications

The U-50k read/write sequential and random CDM performance benchmarks are detailed in the following Table 3 and Table 4.

**Table 3: Read/Write Performance in SuperSpeed mode<sup>2</sup>**

Capacity	Sequential Read (MBPS)	Sequential Write (MBPS)	Random Read 4K (IOPS)	Random Write 4K (IOPS)
16 GBytes	120	42.9	3,220	930
32 GBytes	136	39.0	3,170	840
64 GBytes	153	63.4	3,090	850
128 GBytes	149	63.9	3,110	860

**Table 4: Read/Write Performance in High-Speed mode<sup>2</sup>**

Capacity	Sequential Read (MBPS)	Sequential Write (MBPS)	Random Read 4K (IOPS)	Random Write 4K (IOPS)
16 GBytes	38.9	20.2	2,450	770
32 GBytes	39.6	19.8	2,410	710
64 GBytes	39.7	19.9	2,400	730
128 GBytes	39.7	19.9	2,380	720

## 4.2 Current Consumption

The drive-level current consumption as a function of operating mode is shown in the following Table 5.

**Table 5: Current Consumption<sup>3</sup>**

Drive Capacity	Sequential Read	Sequential Write	Random Read 4K	Random Write 4K	Idle	Unit
16 GBytes	142	141	98	106	81	mA
32 GBytes	148	144	97	106	81	
64 GBytes	157	181	98	107	81	
128 GBytes	159	182	97	106	80	

<sup>2</sup> The values are measured using CrystalDiskMark 5.1.2 x64 (CDM) with Seq Q1T1 and 4KiB Q8T8. Performance depends on flash type and number, file/cluster size, and burst speed.

<sup>3</sup> All values are the typical recorded at 25 °C, with 5V supply voltage at fastest CrystalDiskMark 5.1.2 x64 (CDM) in SuperSpeed mode.

## 4.3 Environmental Specifications

### 4.3.1 Recommended Operating Conditions

The recommended operating conditions for the U-50k USB flash drives are provided in the following Table 6.

**Table 6: Recommended Operating Conditions<sup>4</sup>**

Parameter	Value
Commercial Operating Temperature	0 °C to 70 °C
Industrial Operating Temperature	-40 °C to 85 °C
Power Supply V <sub>CC</sub> Voltage	5.0 V ± 10%

### 4.3.2 Recommended Storage Conditions

The recommended storage conditions are listed in the following Table 7.

**Table 7: Recommended Storage Conditions**

Parameter	Value
Commercial Storage Temperature	-40 °C to 85 °C <sup>5</sup>
Industrial Storage Temperature	-40 °C to 85 °C <sup>5</sup>

### 4.3.3 Shock, Vibration and Humidity

The maximum shock, vibration and humidity conditions are listed in the following Table 8.

**Table 8: Shock, Vibration and Humidity**

Parameter	Value
Non-Operating Shock	1,500 g (JESD22-B110, IEC 60068-2-27)
Non-Operating Vibration	20 g (IEC 60068-2-6, MIL-STD-883 M2007.3)
Humidity (Non-Condensing)	85% RH 85 °C, 1000 hrs (JESD22-A101)

<sup>4</sup> Adequate airflow is required to ensure the drive temperature, as reported in the S.M.A.R.T. data, does not exceed the specified maximum operating temperature.

<sup>5</sup> The retention at high temperature is reduced. The acceleration factor at 85°C compared with 40°C is 170, i.e. the initial endurance at 10 years@40°C is reduced to 22 days@85°C.



#### 4.4 Regulatory Compliance

The U-50k devices comply with the standards listed in the following Table 9.

**Table 9: Regulatory Compliance**

Abbreviation	Regulation/ Standard
EMC	CE – 2014/30/EU FCC – 47 CFR Part 15 UKCA – S.I. 2016 No. 1091 and S.I. 2012 No. 3032
RoHS	2011/65/EU with 2015/863/EU and 2017/2102/EU
REACH	1907/2006/EU and 207/2011/EU
WEEE	2012/19/EU

#### 4.5 Mechanical Specifications

Physical dimensions (including cap) are detailed in the following Table 10. Figure 3 on page 13 illustrates the U-50k dimensions.

**Table 10: Measured Physical Dimensions**

Physical Dimensions		Unit
Length	67.8±0.4	mm
Width	18.0±0.2	
Thickness (Max)	8.3±0.2	
Weight (Max Capacity)	10	g

## 4.6 Reliability and Endurance

The Mean Time Between Failure (MTBF) is specified to exceed the value listed in the following Table 11. Data reliability with effective error tolerance and data retention at the beginning and end of life is also provided.

**Table 11: Reliability**

Parameter	Value
MTBF (at 25 °C)	> 3,000,000 hours
Data Reliability	< 1 Non-Recoverable Error per 10 <sup>16</sup> Bits Read
Data Retention	10 Years at Start (JESD47), 1 Year at EOL

Endurance represented as TeraBytes Written (TBW) is provided in the following Table 12.

**Table 12: Endurance<sup>6</sup>**

Drive Capacity	TeraBytes Written (TBW) @ Seq. Write 128kB Operation <sup>7</sup>	TeraBytes Written (TBW) @ Random Write 128kB Operation <sup>7</sup>	TeraBytes Written (TBW) @ Random Write 4kB Operation <sup>7</sup>
16 GBytes	52	6.7	2.0
32 GBytes	101	11.6	3.2
64 GBytes	197	18.5	5.8
128 GBytes	396	37.1	10.7

## 4.7 Drive Geometry Specification

**Table 13: Drive Geometry**

Raw Capacity	Total LBA	User Addressable Bytes
	Decimal	(Unformatted)
16 GBytes	31,326,208	16,039,018,496
32 GBytes	62,533,296	32,017,047,552
64 GBytes	125,045,424	64,023,257,088
128 GBytes	250,069,680	128,035,676,160

<sup>6</sup> The Endurance values depend strongly on the use case, the preconditioning, the operation sequence, use of trim commands and usage level of the flash drive. The given values are for orientation only.

<sup>7</sup> Sequential write 128kB simulates a continuous stream recording on a drive which has been preconditioned with a sequential write of the complete drive, Random Write 128KB or 4KB represent data logging applications with large or small block sizes.

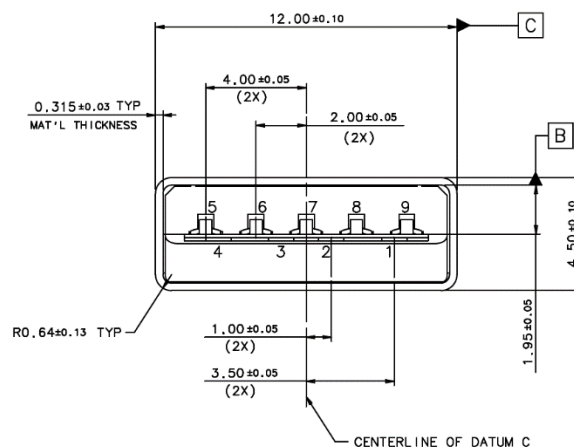
## 5. Electrical Interface

- USB3 Type-A connector, 9pin
- USB 3.1 Gen1 SuperSpeed interface, USB2.0 high-speed and 1.1 full-speed compatible

**Table 14: Electrical pinout from device and host view.**

Pin	Signal device view	Signal host view	Description host view
1	V_Bus	V_Bus	Operating voltage
2	D-	D-	Data signal pair
3	D+	D+	Data signal pair
4	GND	GND	Power Ground
5	SSTX-	SSRX-	Host receive -
6	SSTX+	SSRX+	Host receive +
7	GND	GND	Signal Ground
8	SSRX-	SSTX-	Host transmit -
9	SSRX+	SSTX+	Host transmit +
Shield			Connector shield

**Figure 2: USB3 Type-A connector pinout**



## 6. Electrical Specification

**Table 15: Absolute Maximum Ratings**

Parameter	Symbol	Min	Max	Unit
Power Supply Voltage	V_Bus	-0.5	6.0	V
Voltage at D+ and D-	V_Data	-0.5	5.0	
Voltage at USB3 pins	V_Data	-0.5	1.8	
Commercial Operating Temperature	T_A	0	70	°C
Industrial Operating Temperature		-40	85	

**Table 16: DC characteristics for SuperSpeed operation (T=25°C, V\_Bus=5V)**

Parameter	Symbol	Density	Min	Typ	Max	Unit
Supply Voltage	V_Bus	all	4.5	5.0	5.50	V
Write current	I_WR	16 GBytes		141	155	mA
		32 GBytes		144	158	
		64 GBytes		181	199	
		128 GBytes		182	200	
Read current	I_RD	16 GBytes		142	156	
		32 GBytes		148	162	
		64 GBytes		157	173	
		128 GBytes		159	175	
Idle current	I_IDL	all		81 <sup>8</sup>	89	
Suspend current	I_CCS	all		1.9	2.5	

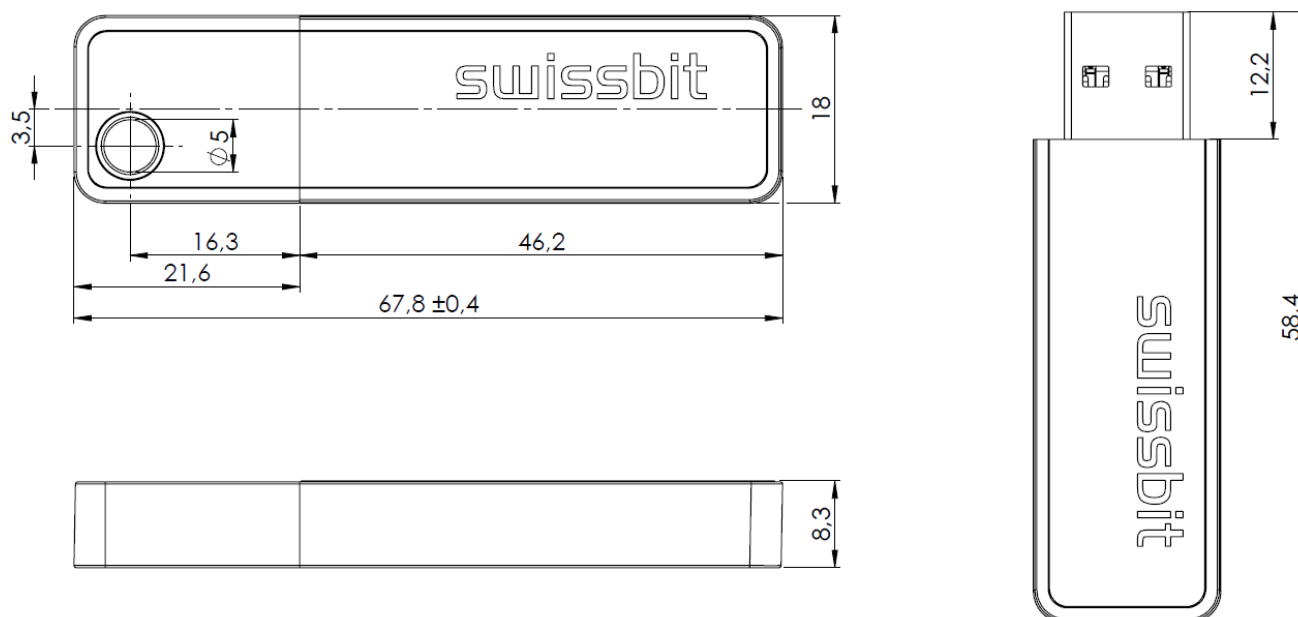
**Table 17: DC characteristics for High-Speed operation (T=25°C, V\_Bus=5V)**

Parameter	Symbol	Density	Min	Typ	Max	Unit
Supply Voltage	V_Bus	all	4.5	5.0	5.50	V
Write current	I_WR	16 GBytes		76	87	mA
		32 GBytes		79	91	
		64 GBytes		84	97	
		128 GBytes		84	97	
Read current	I_RD	16 GBytes		75	90	
		32 GBytes		76	91	
		64 GBytes		76	91	
		128 GBytes		76	91	
Idle current	I_IDL	all		44 <sup>8</sup>	49	mV
Suspend current	I_CCS	all		2.1	2.5	
High Speed Idle Level	V_HSOI	all	-10		10	
High Speed Data Signaling LOW	V_HSOL	all	-10		10	
High Speed Data Signaling HIGH	V_HSOH	all	360		440	
Chirp J Level (differential)	V_CHIRPJ	all	360		440	
Chirp K Level (differential)	V_CHIRPK	all	-440		-360	

<sup>8</sup> Typically 5 minutes after power on the device performs a background data care management, that needs up to 160mA in SuperSpeed and 115mA in High-Speed mode.

## 7. Package Mechanical

Figure 3: Mechanical Dimensions for U-50k



All dimensions are in millimeters, tolerance:  $\pm 0.2$

## 8. ATA Pass-Through commands (Identify Device and S.M.A.R.T.)

### 8.1 ATA Pass-Through commands

Additional to the standard SCSI commands the device also supports the ATA Pass-Through commands.

**Table 18: ATA PASS-THROUGH(x) commands**

SCSI command	OpCode	Description
ATA PASS-THROUGH(12)	A1h	Write and read ATA registers to send commands and read information
ATA PASS-THROUGH(16)	85h	

<http://www.t10.org/ftp/t10/document.04/04-262r8.pdf>

**Table 19: ATA register addressing**

Offset address	Input	Output	Type	Identify device	e.g. SMART commands
0	Data		Word		
1	Feature	Error	Byte	xx	yyh*
2	Sector count		Byte	xx	01h
3	LBA_Low		Byte	xx	xx
4	LBA_Mid		Byte	xx	4Fh
5	LBA_High		Byte	xx	C2h
6	Drive/head		Byte	Eoh	Eoh
7	Command	Status	Byte	ECh	Boh

\* see below

### 8.2 Identify Device

The Identify Device returns a identify sector compatible to ATA and SATA devices.  
Here an example of the interpretation of this sector.

**Table 20: Identify Device Information**

Word(s)	Default Value		Total Bytes	Data Field Type Information
0	0040h		2	Standard Configuration Fixed (optional 848Ah for removable)
...	...	...	...	...
10-19	aaaa*		20	Serial number in ASCII (right-justified)
...	...	...	...	...
23-26	XXXX*		8	Firmware revision in ASCII (big-endian byte order in Word)
27-46	XXXX*		40	Model number in ASCII (right-justified)
...	...	...	...	...
60-61	XXXXh		4	Total number of sectors addressable in LBA mode
...	...	...	...	...
82	0101h 7701h* 4063h*		2	Command set: SMART feature set, service interrupt
...	...	...	...	...
85	000Xh 0701h* 4063h*		2	Command set enabled: SMART feature set enabled/disabled
...	...	...	...	...
255	XXA5h		2	Integrity Word

\* Values depend on device configuration.

### 8.3 S.M.A.R.T. commands

The intent of the SMART command feature set is to protect user data and minimize the likelihood of unscheduled system downtime that may be caused by predictable degradation and/or fault of the device. By monitoring and storing critical performance and calibration parameters, SMART feature set devices attempt to predict the likelihood of a near-term degradation or fault condition. Providing the host system the knowledge of a negative reliability condition allows the host system to warn the user of the impending risk of a data loss and advise the user of the appropriate action.

All S.M.A.R.T. commands have the command code Boh. The different commands are selected by the Feature register.

**Table 21: S.M.A.R.T. Features Supported**

Operation	Feature	Sect Count	LBA low	LBA mid	LBA high	DRV head	Com-mand
S.M.A.R.T. Read Data	D0h	01h	xx	4Fh	C2h	E0h	Boh
S.M.A.R.T. Read Attribute Thresholds	D1h	01h	xx	4Fh	C2h	E0h	Boh
S.M.A.R.T. Enable Operations	D8h	xx	xx	4Fh	C2h	E0h	Boh
S.M.A.R.T. Disable Operations	D9h	xx	xx	4Fh	C2h	E0h	Boh
S.M.A.R.T. Return Status	DAh	xx	xx	4Fh	C2h	E0h	Boh

All commands are aborted, if the LBA signature is invalid.

#### 8.3.1 S.M.A.R.T. Read Data (Doh)

When the drive receives the S.M.A.R.T. Read Data subcommand, it returns one sector (512 bytes) of data. See the following table for the data structure of this sector.

**Table 22: S.M.A.R.T. Data Structure**

Byte(s)	Value	Description
0-1	0010h	S.M.A.R.T. structure version
2-361	XXh	Attribute entries 1 to 30 (see Table 23)
362	00h	Off-line data collection status (no off-line data collection started)
363	00h	Self-test execution status byte (self-test completed)
364-365	0000h	Total time, in seconds, to complete off-line data collection
366	00h	Vendor specific
367	00h	Off-line data collection capability (no off-line data collection)
368-369	0003h	S.M.A.R.T. capabilities
370	00h	No Error logging capability
371	00h	Vendor specific
372	00h	Short self-test routine recommended polling time, in minutes
373	00h	Extended self-test routine recommended polling time, in minutes
374-385	00h	Reserved
386-387	0004h	SMART Version
388-510	XXh	Vendor specific
511	XXh	Data structure checksum

### 8.3.2 S.M.A.R.T. Attribute Entry Structure

Each attribute entry (Bytes 2–361) consists of 12 bytes. See the following table for the data structure of each entry.

**Table 23: Attribute Entry**

Offset Byte(s)	Value	Description
0	XXh	Attribute ID (see Table 24)
1–2	XXXXh	Flags (little-endian) Bit0: Advisory (0) or Prefailure (1) Bit1: Not used (0) or updated during normal operation (1)
3	XXh	Current value as a percentage 64h = 100%
4	XXh	Worst value as a percentage 64h = 100%
5–10	XXXXh	Raw value (little-endian)
11	00h	Reserved

### 8.3.3 S.M.A.R.T. Attributes

The drives support the S.M.A.R.T. attributes listed in the following table.

The Threshold values can be read out with the S.M.A.R.T. Read Attribute Thresholds command (D1h)

The first attributes (196, 213, 229) are “Pre-Fail” type, while all other are Advisory (Old Age).

**Table 24: S.M.A.R.T. Attributes**

ID dec	ID hex	Value	Worst	Thres-hold	Attribute	Description	RAW values Offset 5–10
196	C4h	X%	X%	25	Spare Block Count	Number of total available NAND spare blocks	Initial (offset 5–7) and current (offset 8–10) number of spare blocks
213	D5h	X%	X%	25	Spare Block Count worst channel	Spare block count for the NAND with the lowest number of remaining spare blocks	Initial (offset 5–7) and current (offset 8–10) number of spare blocks of the channel with the lowest current number of spare blocks
229	E5h	X%	X%	2	Total Erase Count	Estimated number of total NAND block erases	Estimated number of total NAND block erases
203	CBh	100	100	0	Total ECC Errors	All recorded ECC errors	Total number of ECC errors (correctable and uncorrectable) (offset 5–8)
204	CCh	100	100	0	Correctable ECC Errors	Total recorded ECC errors that were corrected during the life of the drive	Total number of correctable ECC errors (offset 5–8)
199	C7h	100	100	0	UDMA CRC Errors	Dummy attribute, included for legacy reasons	This value is fixed at 0.
232	E8h	100	100	0	Total Number of Reads	Total number of NAND READ commands	Total number of NAND READ commands
12	0Ch	100	100	0	Power-On Count	Count of power-on events	Number of power cycles (offset 5–8)
241	F1h	100	100	0	Total LBAs Written	Total amount of data written to the drive	Total number of LBAs written to the disk, divided by 65536
242	F2h	100	100	0	Total LBAs Read	Total amount of data read from the drive	Total number of LBAs read from the disk, divided by 65536
214	D6h	100	100	0	Management Block status	Total number of times the management block has been updated	Management block write count (offset 5–8)
215	D7h	X%	X%	0	Trim Status	Amount of device content that is currently in the trimmed state	This value is fixed at 0.



ID dec	ID hex	Value	Worst	Thres-hold	Attribute	Description	RAW values Offset 5-10
194	C2h	X°C	Max °C	0	Temperature Status	Device temperature in Celsius (°C)	Current (offset 5) / Min (offset 6) / Max temperature (offset 7)

\* These threshold values are changeable using the Write Attribute Thresholds command.

### 8.3.4 S.M.A.R.T. Read Attribute Thresholds (D1h)

When the drive receives the S.M.A.R.T. Read Attribute Thresholds subcommand, it returns one sector (512 bytes) of data similar as S.M.A.R.T. Read data sector, but with the threshold value in offset 1 of each attribute (see Table 24).

### 8.3.5 S.M.A.R.T. Enable Operations (D8h)

This command enables access to the S.M.A.R.T. capabilities of the drive. The state of SMART (enabled or disabled) is preserved across power cycles.

### 8.3.6 S.M.A.R.T. Disable Operations (D9h)

This command disables access to the S.M.A.R.T. capabilities of the drive. The state of SMART (enabled or disabled) is preserved across power cycles.

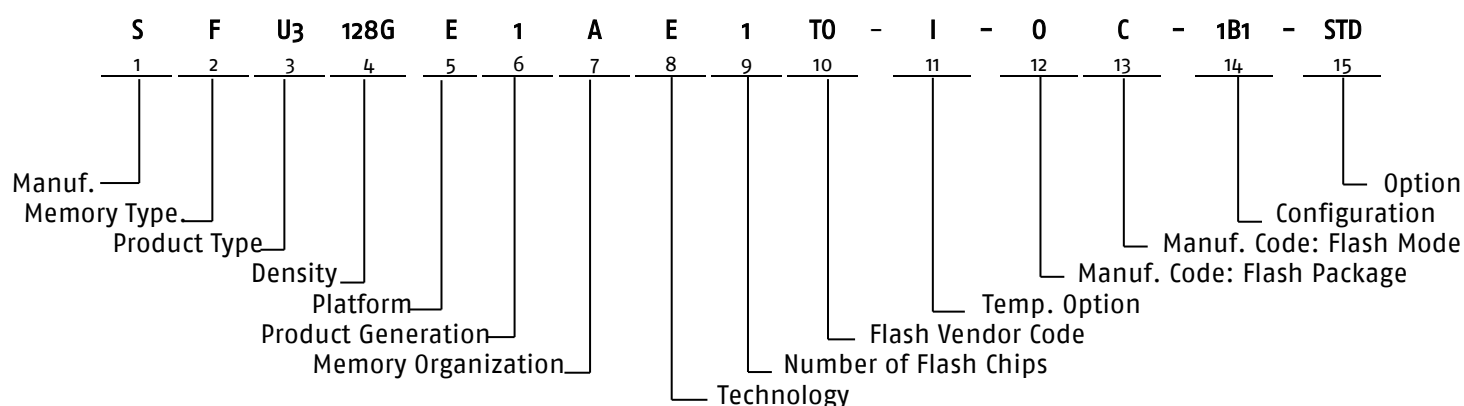
### 8.3.7 S.M.A.R.T. Return Status (DAh)

**Table 25: S.M.A.R.T. Return Status**

Operation	Feature	Sect Count	LBA low	LBA mid	LBA high	DRV head	Com-mand
Command S.M.A.R.T. Return Status	DAh	xx	xx	4Fh	C2h	E0h	Boh
<b>Response</b>							
S.M.A.R.T. Return Status OK	xx	xx	xx	4Fh	C2h	xx	xx
S.M.A.R.T. Return Status Pre-FAIL*	xx	xx	xx	F4h	2Ch	xx	xx

\* If a threshold exceeded condition exists for either the Spare Block Count Worst Channel attribute or the Erase Count attribute, the device will set the Cylinder Low register to F4h and the Cylinder High register to 2Ch. In this case the drive should be replaced soon.

## 9. Part Number Decoder



### 9.1 Manufacturer

Swissbit code	S
---------------	---

### 9.2 Memory Type

Flash	F
-------	---

### 9.3 Product Type

USB 3.1 Flash Drive	U3
---------------------	----

### 9.4 Density

16 GBytes	016G
32 GBytes	032G
64 GBytes	064G
128 GBytes	128G

### 9.5 Platform

Full size USB drive	E
---------------------	---

### 9.6 Product Generation

First generation	1
------------------	---

### 9.7 Memory Organization

x8	A
----	---

### 9.8 Technology

U-5xx platform UFD	E
--------------------	---

## 9.9 Number of Flash Chips

1 Flash	1
2 Flash	2

## 9.10 Flash Code

Toshiba / Kioxia	TO
------------------	----

## 9.11 Temperature Option

Industrial Temperature Range: -40 °C to 85 °C	I
Standard Temperature Range: 0 °C to 70 °C	C

## 9.12 Die Classification

MLC MONO (single die package)	G
MLC DDP (dual die package)	L
MLC QDP (quad die package)	H
MLC ODP (oct die package)	O

## 9.13 Pin Mode

	BGA	TSOP
Single nCE and Single R/nB	A	S
Dual nCE and Dual R/nB	B	T
Quad nCE and Quad R/nB	C	U

## 9.14 Configuration XYZ

### X = Configuration

Configuration	X
Removable	1

### Y = Firmware Revision

FW Revision	Y
durabit™ Revision 1	A
durabit™ Revision 2	B

### Z = Optional setting

Optional Setting	Z
Default (MLC)	1
pSLC (pseudo SLC)	P

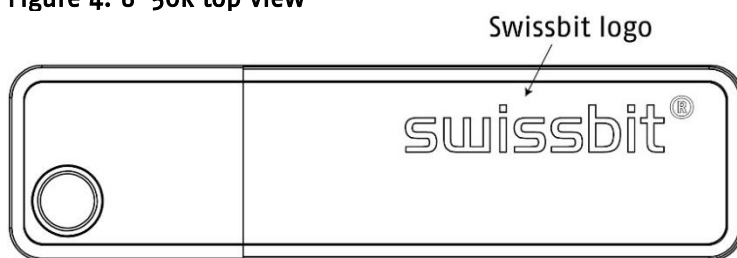
## 9.15 Option

Swissbit / Standard	STD
Customized version	XXX

## 10. Marking Specification

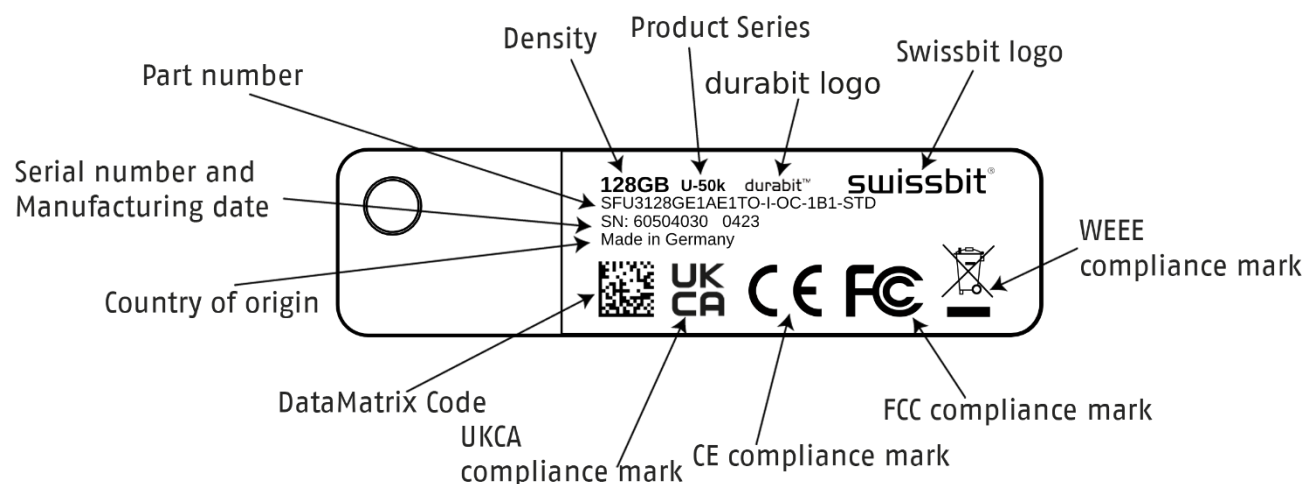
### 10.1 Top View

Figure 4: U-50k top view



### 10.2 Bottom View

Figure 5: U-50k bottom view



## 11.Revision History

**Table 26: Document Revision History**

Date	Revision	Description	Revision Details
27-Aug-2018	0.91	First preliminary release	
16-Oct-2018	0.92	Small adjustments in Table 8	
11-Jun-2019	1.00	Initial release	Doc. req. no. 2984
26-Jan-2023	1.01	Added Firmware Revision 2	Doc. req. no. 6014

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